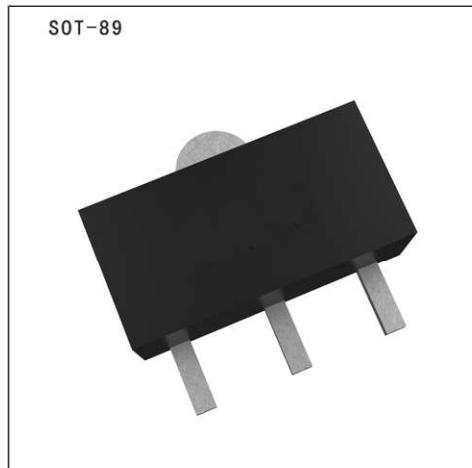


● Features

High collector to emitter voltage: $V_{CEO} > -120V$.



● Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-120	V
Collector-emitter voltage	V_{CEO}	-120	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-0.7	A
Collector current (pulse) *1	$I_{C(pu)}$	-1.2	A
Collector power dissipation	P_c	2	W
Junction temperature	T_j	150	$^\circ C$
Storage temperature	T_{stg}	-55 to +150	$^\circ C$

*1. PW≤10ms,duty cycle≤50%

● Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -120V, I_E = 0$			-100	nA
Emitter cutoff current	I_{EBO}	$V_{EB} = -5V, I_C = 0$			-100	nA
DC current gain *	h_{FE}	$V_{CE} = -1V, I_C = -100mA$	90	200	400	
		$V_{CE} = -1V, I_C = -5.0mA$	45	200		
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_C = -500mA, I_B = -50mA$		-0.4	-0.6	V
Base-emitter saturation voltage *	$V_{BE(sat)}$	$I_C = -500mA, I_B = -50mA$		-0.9	-1.5	V
Base-emitter voltage *	V_{BE}	$V_{CE} = -10V, I_C = -10mA$	-550	-620	-650	mV
Output capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1.0MHz$		14		pF
Transition frequency	f_T	$V_{CE} = -10V, I_E = 10mA$		75		MHz

* PW≤350μs,duty cycle≤2%

● hFE Classification

Marking	KR	KQ	KP
hFE	90~180	135~270	200~400

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